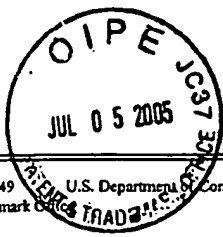
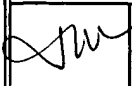
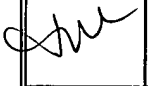
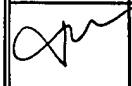
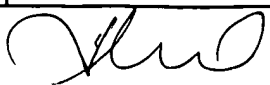


USPTO Form 1449 Patent and Trademark Office INFORMATION DISCLOSURE STATEMENT				Attorney Docket No. 2846/2112		Serial No. 10/660,348		
				Applicant(s): Ren et al.				
				Filing Date: September 11, 2003		Group: 1775		
U.S. PATENT DOCUMENTS								
Examiner Initial		Patent No.	Date	Name	Class	Subclasses	Filing Date (if appropriate)	
		6,855,202	February 15, 2005	Alivisatos et al.	117	68	November 20, 2002	
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FOREIGN PATENT DOCUMENTS								
Examiner Initial		Document No.	Publication Date	Country	Class	Subclasses	Translation	
							YES	NO
OTHER DOCUMENTS (including Author, Title, Date, Pertinent Pages, etc.)								
	A	International Search Report based on PCT/US03/28530 dated April 7, 2005.						
EXAMINER					DATE CONSIDERED			
					10/13/05			
<small>*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.</small>								
<small>**Copies of references not provided at the time of this submission.</small>								



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FOREIGN PATENT DOCUMENTS								
Examiner Initial		Document No.	Publication Date	Country	Class	Subclasses	Translation	
							YES	NO
OTHER DOCUMENTS (including Author, Title, Date, Pertinent Pages, etc.)								
	A	Park, W.I. et al., <u>Metalorganic Vapor-Phase Epitaxial Growth of Vertically Well-Aligned ZnO Nanorods</u> , Applied Physics Letters, 2002, Vol. 80, No. 22, pp. 4232-4234.						
	B	Park, W.I. et al., <u>ZnO Nanoneedles Grown Vertically on Si Substrates by Non-Catalytic Vapor-Phase Epitaxy</u> , Advanced Materials, 2002, Vol. 14, No. 24, pp. 1841-1843.						
	C	Suscavage, M. et al., <u>High Quality Hydrothermal ZnO Crystals</u> , MRS Internet J. Nitride Semicond. Res. 4S1, G3.40 (1999), 6 pgs.						
EXAMINER 					DATE CONSIDERED 10/13/05			
*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.								
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